**PCN Number:** 20140915000 PCN Date: 09/23/2014 Oualification of TI Chengdu as Additional Assembly and Test Site for Select Devices on Title: X2SON and WQFN Package **Customer Contact:** PCN Manager **Phone:** +1(214)480-6037 **Dept: Quality Services Estimated Sample** Date provided at Proposed 1st Ship Date: 12/23/2014 **Availability:** sample request **Change Type:** Assembly Site Design Wafer Bump Site **Assembly Process** Data Sheet Wafer Bump Material **Assembly Materials** Part number change Wafer Bump Process Mechanical Specification Test Site Wafer Fab Site Packing/Shipping/Labeling **Test Process** Wafer Fab Materials Wafer Fab Process

#### **PCN Details**

## **Description of Change:**

Texas Instruments Incorporated is announcing the qualification of TI Chengdu (CDAT) as Additional Assembly and Test Site for select devices listed in the "Product Affected" Section. Current assembly sites are as follows and material differences as follows.

	Existing Sites	Additional Site		
Assembly/Test Sites	TI-CLARK, CARZ, NSE	CDAT		

Test coverage, insertions, conditions will remain consistent with current testing and verified with test MQ.

## **Reason for Change:**

Continuity of supply

# Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

#### Changes to product identification resulting from this PCN:

Assembly Site		
TI-CLARK	Assembly Site Origin (22L)	ASO: QAB
CARZ	Assembly Site Origin (22L)	ASO: CSZ
NSE	Assembly Site Origin (22L)	ASO: NSE
TI Chengdu (CDAT)	Assembly Site Origin (22L)	ASO: CDA

ASSEMBLY SITE CODES: TI-CLARK = I , CARZ = F , NSE = J, CDAT = 8

Sample product shipping label (not actual product label)





(1P) \$N74L\$07N\$R (Q) 2000 (D) 0336 (31T) LOT: 3959047MLA (4W) TKY(1T) 7523483\$I2 (P) (2P) REV: (V) 0033317 (20L) CSO: SHE (21L) CCO:USA (22L) ASO: MLA (23L) ACO: MYS

Product Affected: Group 1 Devices					
BQ294502DRVR	BQ294592DRVT	TPS51225RUKR	TPS61158DRVR		
BQ294502DRVT	BQ294602DRVR	TPS51225RUKT	TPS62061DSGR		
BQ294504DRVR	BQ294602DRVT	TPS51275BRUKR	TPS62061DSGT		
BQ294504DRVT	BQ294604DRVR	TPS51275BRUKT	TPS62063DSGR		
BQ294515DRVT	BQ294604DRVT	TPS51275CRUKR	TPS62063DSGT		
BQ294524DRVR	SN51285ARUKR	TPS51275CRUKT	TPS62065DSGR		
BQ294524DRVT	TPS22967DSGR	TPS51275RUKR	TPS62065DSGT		
BQ294532DRVR	TPS22967DSGT	TPS51275RUKT	TPS62080DSGR		
BQ294532DRVT	TPS51225BRUKR	TPS51285ARUKR	TPS62080DSGT		
BQ294582DRVR	TPS51225BRUKT	TPS51285ARUKT	TPS62082DSGR		
BQ294582DRVT	TPS51225CRUKR	TPS51285BRUKR	TPS62082DSGT		
BQ294592DRVR	TPS51225CRUKT	TPS51285BRUKT			
<b>Product Affected: Gro</b>	up 2 Devices				
TLV70712PDQNT	TLV707285PDQNT	TLV71718PDQNT	TPS3839G33DQNT		
TLV70718PDQNT	TLV70732DQNT	TLV71727PDQNT	TPS3839K33DQNT		
TLV70719PDQNT	TLV70736PDQNT	TLV71729PDQNT	TPS3839K50DQNT		
TLV70725PDQNT	TLV71320DQNT	TLV71733PDQNT	TPS3839L30DQNT		
TLV707285DQNT	TLV717185PDQNT	TPS3839G18DQNT			

Qualification Plan - Group 1 Device							
This qualification has been developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.							
Qualification Schedule:	Start:	Sept 2014 End:		End:	Dec 2014		
Qual	Vehicle # 1: B	Q294	504DRVR (M	SL2-260	C)		
Package Construction Details							
Assembly Site:	TI CHENGDU		Mold Cor	mpound:	42086	208625	
# Pins-Designator, Family:	6-DRV, WQFN		Mount Co	mpound:	42077	4207768	
Lead frame (Finish, Base):	NiPdAu, Cu		Во	nd Wire:	0.96 №	.96 Mil Dia., Cu	
Qualification:  Plan  Test Results							
Reliability Test	Conditions	Conditions			Sample Size/Fail		
Reliability Test	Conditions				Lot#1	Lot#2	Lot#3
Electrical Characterization	Electrical Characterization -				30/0	30/0	30/0
**High Temp. Storage Bake 170C (420hrs)				77/0	77/0	77/0	
**Autoclave 121C	121C 121C, 2 atm (96		Hrs)		77/0	77/0	77/0
**T/C -65C/150C	-65C/+150C	-65C/+150C (500 (			77/0	77/0	77/0
Manufacturability	(per mfg. Site spec		ecification)		1/0	1/0	1/0
Moisture Sensitivity	(level 2 @ 260C peak +5/-0C) 12/0 12/0 1		12/0				
Notes **- Preconditioning sequence: Level 2-260C.							

Qual Vehicle # 2: TPS51285BRUKR (MSL2-260C)						
Package Construction Details						
Assembly Site:	mbly Site: TI CHENGDU		Mold Compound:	4208625		
# Pins-Designator, Family:	20-	20-RUK, WQFN Mount Compound:		4207768		
Lead frame (Finish, Base):	NiP	dAu, Cu	Bond Wire:	0.96 Mil Dia., Cu		
Qualification: 🛛 Plan		Test Results		<u>'</u>		
Reliability Test		Conditions		Sample Size/Fail		
Reliability Test		Conditions		Lot#1	Lot#2	Lot#3
Electrical Characterization		-		30/0	30/0	30/0
**High Temp. Storage Ba	ке	170C (420hrs)		77/0	77/0	77/0
**Autoclave 121C		121C, 2 atm (96		77/0	77/0	77/0
**T/C -65C/150C		-65C/+150C (500	) Cyc)	77/0	77/0	77/0
Solderability		Pb-free		22/0	22/0	22/0
Manufacturability		(per mfg. Site spe		1/0	1/0	1/0
Moisture Sensitivity		(level 2 @ 260C p		12/0	12/0	12/0
		equence: Level 2-2				
Qua	ıl Ve		.158DRVR (MSL2-260	OC)		
		Package Const	ruction Details	1		
Assembly Site:	TI	CHENGDU	Mold Compound:	4208625		
# Pins-Designator, Family:	6-E	RV, WQFN	Mount Compound:	4207768		
Lead frame (Finish, Base):	NiP	dAu, Cu	Bond Wire:	0.96 Mi	l Dia., Au	
Qualification: 🔀 Plan		Test Results				
Reliability Test		Conditions		Sample Size/Fail		
				Lot#1	Lot#2	Lot#3
Electrical Characterization -			30/0	30/0	30/0	
**High Temp. Storage Ba				77/0	77/0	77/0
**Autoclave 121C		121C, 2 atm (96 Hrs)		77/0	77/0	77/0
**T/C -65C/150C		-65C/+150C (500 Cyc)		77/0	77/0	77/0
Manufacturability		(per mfg. Site specification)		1/0	1/0	1/0
Notes **- Preconditioning sequence: Level 2-260C.						
Qua	II V		2065DSGR (MSL2-260	JC)		
Package Construction Details						
Assembly Site:		CHENGDU Mold Compound:		4208625		
# Pins-Designator, Family:		DSG, WQFN Mount Compound:				
Lead frame (Finish, Base):			l Dia., Cu			
Qualification:						
Reliability Test		Conditions			ple Size/	
Electrical Characterization -		_		Lot#1 30/0	Lot#2 30/0	Lot#3 30/0
**High Temp. Storage Ba	(P	170C (420hrs)		77/0	77/0	77/0
**Autoclave 121C	ι	121C, 2 atm (96	Hrs)	77/0	77/0	77/0
**T/C -65C/150C		-65C/+150C (500		77/0	77/0	77/0
Manufacturability		(per mfg. Site spe		1/0	1/0	1/0
	าต ระ			1,0		<u> </u>
Notes **- Preconditioning sequence: Level 2-260C.						

Qualification Data - Group 2 Device						
This qualification has been developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.						
		•		rications.		
Qua	al Vehicle: TLV7072	8PDQNR (MSL1-260	C)			
	Package Const	ruction Details	_			
Assembly Site:	TI CHENGDU	Mold Compound:	4210087			
# Pins-Designator, Family:	4-DQN, X2SON	Mount Compound:	422146	0		
Lead frame (Finish, Base):	NiPdAu/NiPdAuAg, Cu	Bond Wire:	0.80 Mi	l Dia., Au		
Qualification:						
Reliability Test	Conditions	Conditions		Sample Size/Fail		
Reliability Test	Conditions			Lot#2	Lot#3	
Electrical Characterization	-	-		Pass	Pass	
**Biased HAST	130C/85%RH (96	130C/85%RH (96Hrs)		77/0	77/0	
**High Temp. Storage Bak	ce 170C (420hrs)	170C (420hrs)		77/0	77/0	
**Autoclave 121C	121C, 2 atm (96	121C, 2 atm (96 Hrs)		77/0	77/0	
**T/C -65C/150C	-65C/+150C (500	-65C/+150C (500 Cyc)		77/0	77/0	
ESD-HBM	1000V	1000V		3/0	3/0	
ESD-CDM	250V	250V		3/0	3/0	
Solderability	Pb-free	Pb-free		22/0	22/0	
Salt Atmosphere	24 Hrs	24 Hrs		22/0	22/0	
Manufacturability	(per mfg. Site spe	ecification)	Pass	Pass	Pass	
		peak +5/-0C)	11/0	12/0	12/0	
Notes **- Preconditioning sequence: Level 1-260C.						

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com